

3A DUAL HIGH-SPEED POWER MOSFET DRIVERS

FEATURES

- High Peak Output Current 3A
- Wide Operating Range 4.5V to 18V
- High Capacitive Load Drive Capability 1800pF in 25nsec
- Short Delay Times <40nsec Typ.
- Matched Rise/Fall Times
- Low Supply Current
 - With Logic "1" Input 3.5mA
 - With Logic "0" Input 350µA
- Low Output Impedance 3.5Ω Typ.
- Latch-Up Protected ..Will Withstand 1.5A Reverse Current
- Logic Input Will Withstand Negative Swing Up to 5V
- ESD Protected4kV
- Pinouts Same as TC1426/27/28; TC4426/27/28

GENERAL DESCRIPTION

The TC4423/4424/4425 are higher output current versions of the new TC4426/4427/4428 buffer/drivers, which, in turn, are improved versions of the earlier TC426/427/428 series. All three families are pin-compatible. The TC4423/4424/4425 drivers are capable of giving reliable service in far more demanding electrical environments than their antecedents.

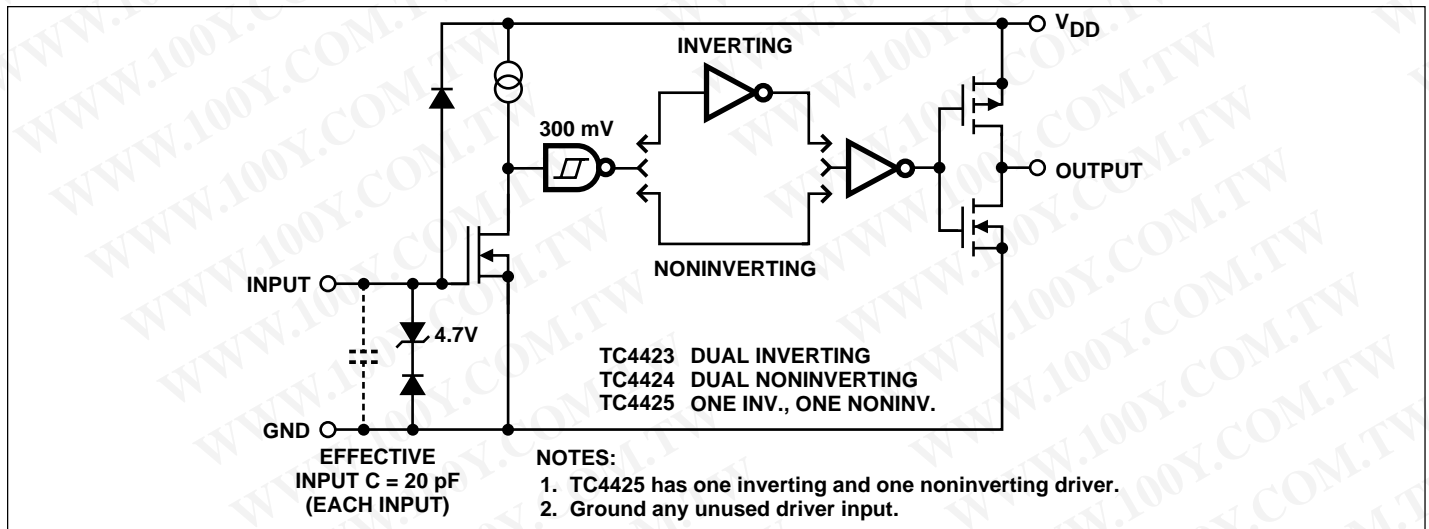
Although primarily intended for driving power MOSFETs, the TC4423/4424/4425 drivers are equally well-suited to driving any other load (capacitive, resistive, or inductive) which requires a low impedance driver capable of high peak currents and fast switching times. For example, heavily loaded clock lines, coaxial cables, or piezoelectric transducers can all be driven from the TC4423/4424/4425. The only known limitation on loading is the total power dissipated in the driver must be kept within the maximum power dissipation limits of the package.

ORDERING INFORMATION

| Part No. | Package | Temperature Range |
|-----------|--------------------|-------------------|
| TC4423COE | 16-Pin SOIC (Wide) | 0°C to +70°C |
| TC4423CPA | 8-Pin Plastic DIP | 0°C to +70°C |
| TC4423EOE | 16-Pin SOIC (Wide) | -40°C to +85°C |
| TC4423EPA | 8-Pin Plastic DIP | -40°C to +85°C |
| TC4423MJA | 8-Pin CerDIP | -55°C to +125°C |
| TC4424COE | 16-Pin SOIC (Wide) | 0°C to +70°C |
| TC4424CPA | 8-Pin Plastic DIP | 0°C to +70°C |
| TC4424MJA | 8-Pin CerDIP | -55°C to +125°C |

| Part No | Package | Temperature Range |
|-----------|-------------------|-------------------|
| TC4424EOE | 16-Pin SO Wide | -40°C to +85°C |
| TC4424EPA | 8-Pin Plastic DIP | -40°C to +85°C |
| TC4425MJA | 8-Pin CerDIP | -55°C to +125°C |
| TC4425COE | 16-Pin SO Wide | 0°C to +70°C |
| TC4425CPA | 8-Pin Plastic DIP | 0°C to +70°C |
| TC4425EOE | 16-Pin SO Wide | -40°C to +85°C |
| TC4425EPA | 8-Pin Plastic DIP | -40°C to +85°C |

FUNCTIONAL BLOCK DIAGRAM



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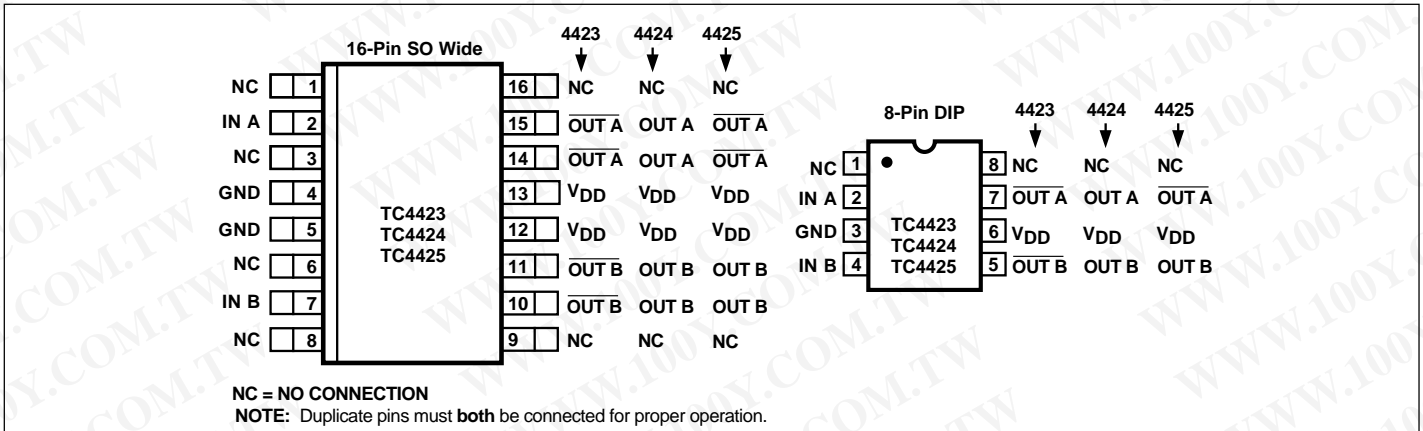
TC4423
TC4424
TC4425

ABSOLUTE MAXIMUM RATINGS

| | |
|--|-------------------------------|
| Supply Voltage | +22V |
| Input Voltage, IN A or IN B | $V_{DD} + 0.3V$ to GND – 5.0V |
| Maximum Chip Temperature | +150°C |
| Storage Temperature Range | – 65°C to +150°C |
| Lead Temperature (Soldering, 10 sec) | +300°C |
| Package Thermal Resistance | |
| CerDIP $R_{\theta J-A}$ | 150°C/W |
| CerDIP $R_{\theta J-C}$ | 55°C/W |
| PDIP $R_{\theta J-A}$ | 125°C/W |
| PDIP $R_{\theta J-C}$ | 45°C/W |

| | |
|---|------------------|
| SOIC $R_{\theta J-A}$ | 155°C/W |
| SOIC $R_{\theta J-C}$ | 75°C/W |
| Operating Temperature Range | |
| C Version | 0°C to +70°C |
| I Version | – 25°C to +85°C |
| E Version | – 40°C to +85°C |
| M Version | – 55°C to +125°C |
| Package Power Dissipation ($T_A \leq 70^\circ\text{C}$) | |
| Plastic DIP | 730mW |
| CerDIP | 800mW |
| SOIC | 470mW |

PIN CONFIGURATIONS



ELECTRICAL CHARACTERISTICS: $T_A = +25^\circ\text{C}$ with $4.5V \leq V_{DD} \leq 18V$, unless otherwise specified.

| Symbol | Parameter | Test Conditions | Min | Typ | Max | Unit |
|--------------------------------|---|--|------------------|-------------|-------------|---------------|
| Input | | | | | | |
| V_{OH} | Logic 1 High Input Voltage | | 2.4 | — | — | V |
| V_{IL} | Logic 0 Low Input Voltage | | — | — | 0.8 | V |
| I_{IN} | Input Current | $0V \leq V_{IN} \leq V_{DD}$ | – 1 | — | 1 | μA |
| Output | | | | | | |
| V_{OH} | High Output Voltage | | $V_{DD} - 0.025$ | — | — | V |
| V_{OL} | Low Output Voltage | | — | — | 0.025 | V |
| R_O | Output Resistance, High | $I_{OUT} = 10\text{ mA}, V_{DD} = 18V$ | — | 2.8 | 5 | Ω |
| R_O | Output Resistance, Low | $I_{OUT} = 10\text{ mA}, V_{DD} = 18V$ | — | 3.5 | 5 | Ω |
| I_{PK} | Peak Output Current | | — | 3 | — | A |
| I_{REV} | Latch-Up Protection Withstand Reverse Current | Duty Cycle $\leq 2\%$ $t \leq 300\ \mu\text{sec}$ | 1.5 | — | — | A |
| Switching Time (Note 1) | | | | | | |
| t_R | Rise Time | Figure 1, $C_L = 1800\text{pF}$ | — | 23 | 35 | nsec |
| t_F | Fall Time | Figure 1, $C_L = 1800\text{pF}$ | — | 25 | 35 | nsec |
| t_{D1} | Delay Time | Figure 1, $C_L = 1800\text{pF}$ | — | 33 | 75 | nsec |
| t_{D2} | Delay Time | Figure 1, $C_L = 1800\text{pF}$ | — | 38 | 75 | nsec |
| Power Supply | | | | | | |
| I_S | Power Supply Current | $V_{IN} = 3V$ (Both Inputs) $V_{IN} = 0V$ (Both Inputs) | — | 1.5 0.15 | 2.5 0.25 | mA mA |

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ELECTRICAL CHARACTERISTICS (Cont.) Over operating temperature range with $4.5V \leq V_{DD} \leq 18V$, unless otherwise specified.

| Symbol | Parameter | Test Conditions | Min | Typ | Max | Unit |
|--------------------------------|--|--|------------------------------------|----------|------------|----------|
| Input | | | | | | |
| V_{IH} | Logic 1 High Input Voltage | | 2.4 | — | — | V |
| V_{IL} | Logic 0 Low Input Voltage | | — | — | 0.8 | V |
| I_{IN} | Input Current $0V \leq V_{IN} \leq V_{DD}$ | | - 10 | — | 10 | μA |
| Output | | | | | | |
| V_{OH} | High Output Voltage | | $V_{DD} - 0.025$ | — | — | V |
| V_{OL} | Low Output Voltage | | — | — | 0.025 | V |
| R_{OH} | Output Resistance, High | $I_{OUT} = 10\text{ mA}, V_{DD} = 18V$ | — | 3.7 | 8 | Ω |
| R_{OL} | Output Resistance, Low | $I_{OUT} = 10\text{ mA}, V_{DD} = 18V$ | — | 4.3 | 8 | Ω |
| I_{PK} | Peak Output Current | | — | 3 | — | A |
| I_{REV} | Latch-Up Protection Withstand Reverse Current | Duty Cycle $\leq 2\%$ Withstand Reverse Current | 1.5 $t \leq 300\ \mu\text{sec}$ | — | — | A |
| Switching Time (Note 1) | | | | | | |
| t_R | Rise Time | Figure 1, $C_L = 1800\text{pF}$ | — | 28 | 60 | nsec |
| t_F | Fall Time | Figure 1, $C_L = 1800\text{pF}$ | — | 32 | 60 | nsec |
| t_{D1} | Delay Time | Figure 1, $C_L = 1800\text{pF}$ | — | 32 | 100 | nsec |
| t_{D2} | Delay Time | Figure 1, $C_L = 1800\text{pF}$ | — | 38 | 100 | nsec |
| Power Supply | | | | | | |
| I_S | Power Supply Current | $V_{IN} = 3V$ (Both Inputs) $V_{IN} = 0V$ (Both Inputs) | — — | 2 0.2 | 3.5 0.3 | mA mA |

NOTE: 1. Switching times guaranteed by design.

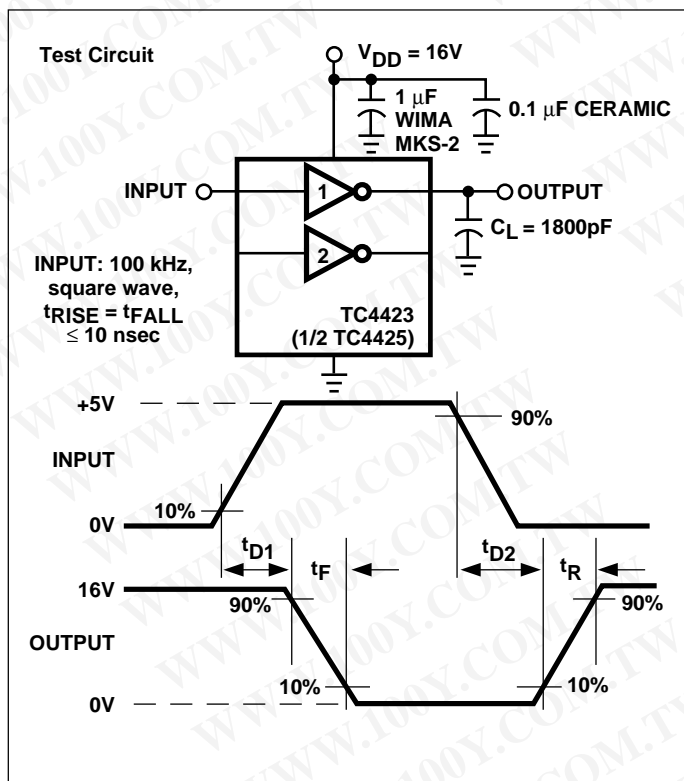


Figure 1. Inverting Driver Switching Time

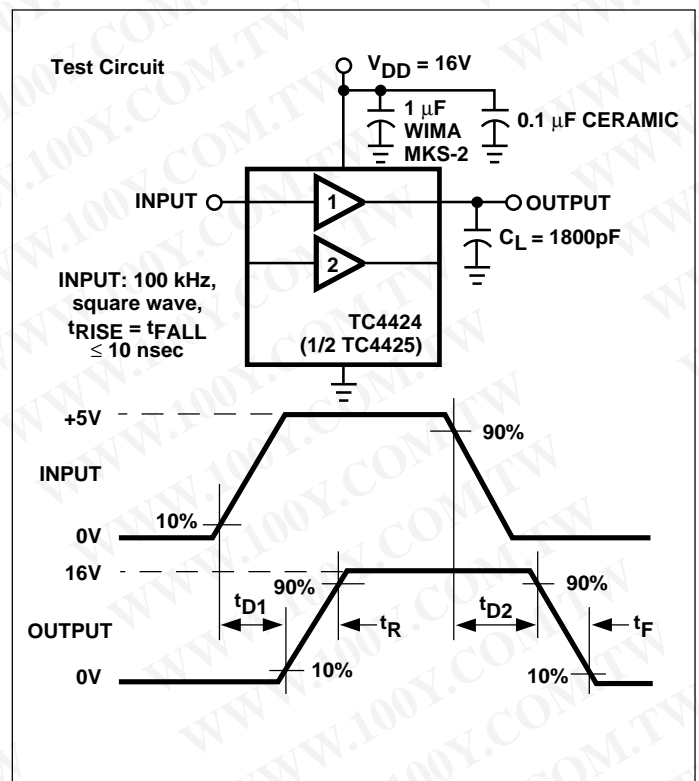


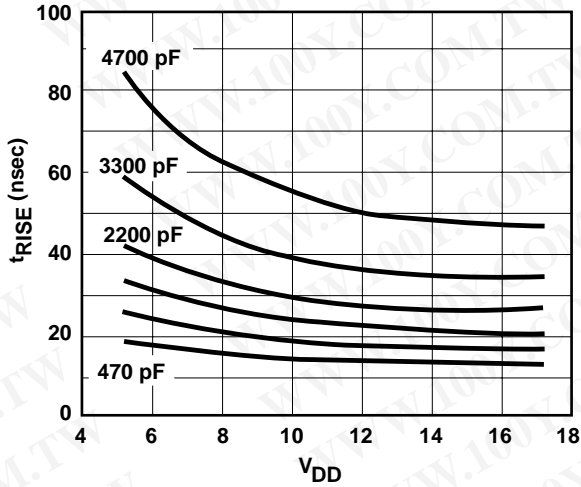
Figure 2. Noninverting Driver Switching Time

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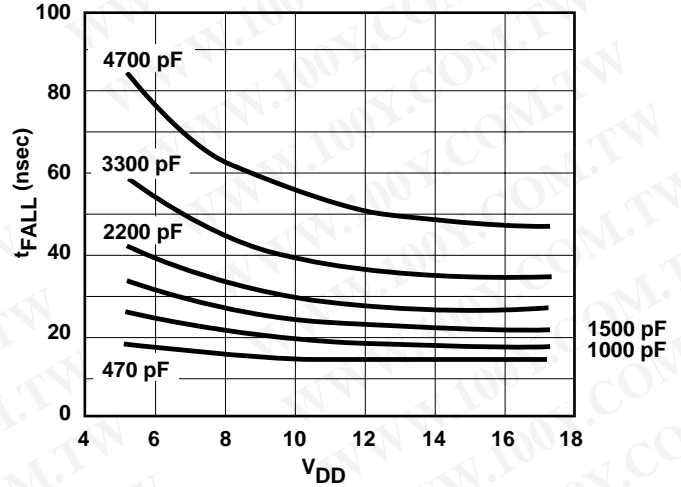
TC4423
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TC4425

TYPICAL CHARACTERISTICS

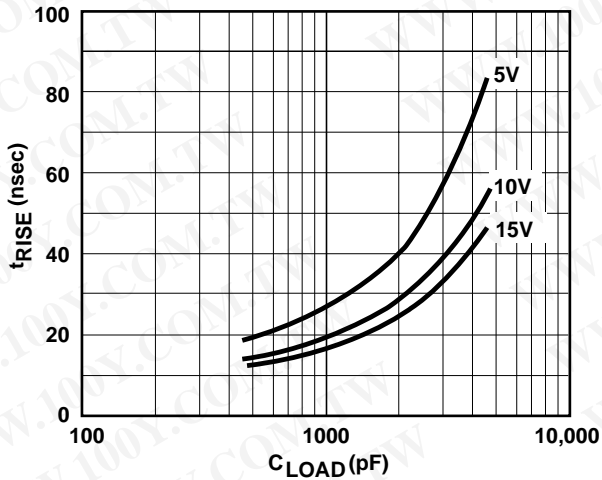
Rise Time vs. Supply Voltage



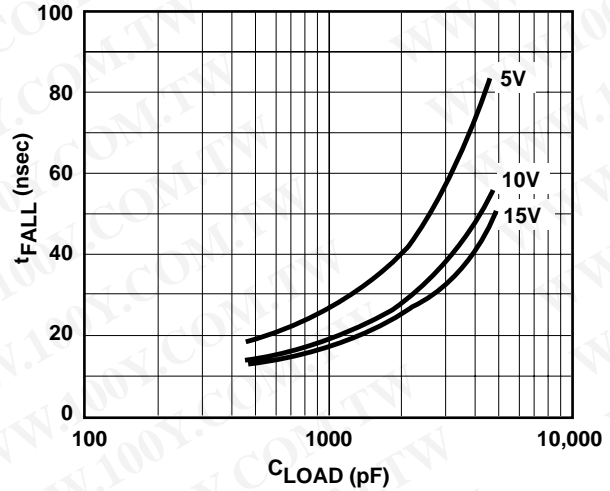
Fall Time vs. Supply Voltage



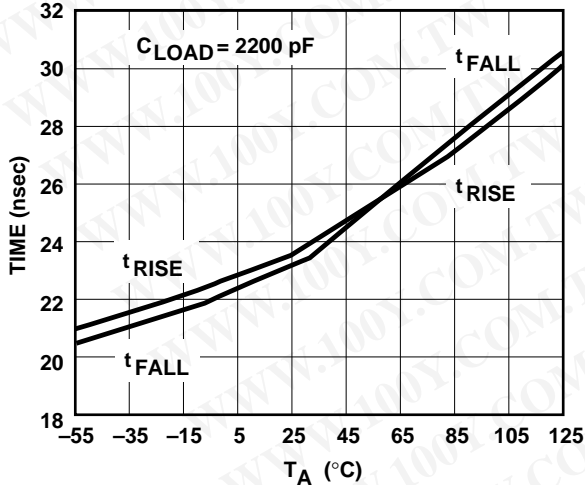
Rise Time vs. Capacitive Load



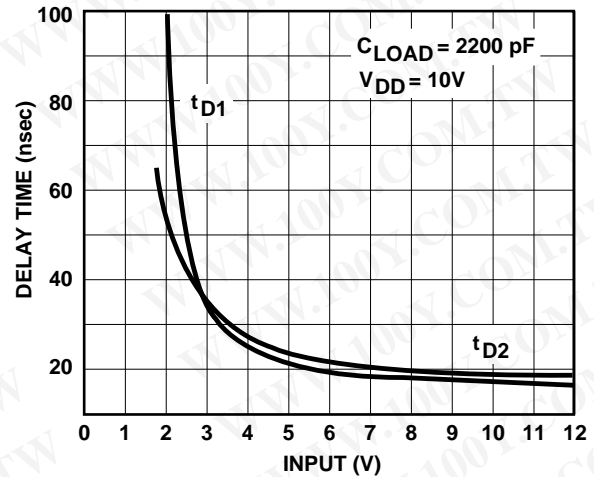
Fall Time vs. Capacitive Load



Rise and Fall Times vs. Temperature



Propagation Delay vs. Input Amplitude

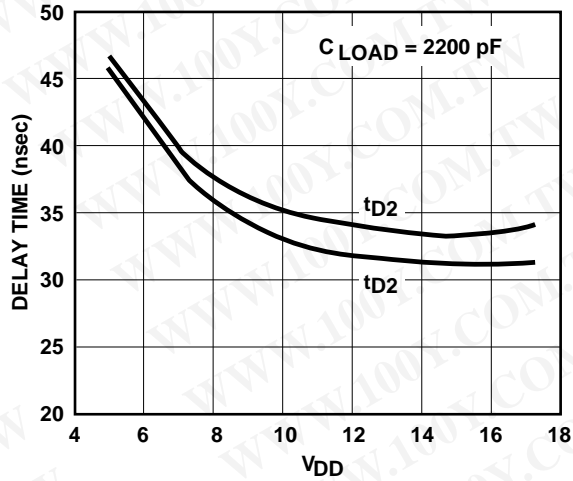


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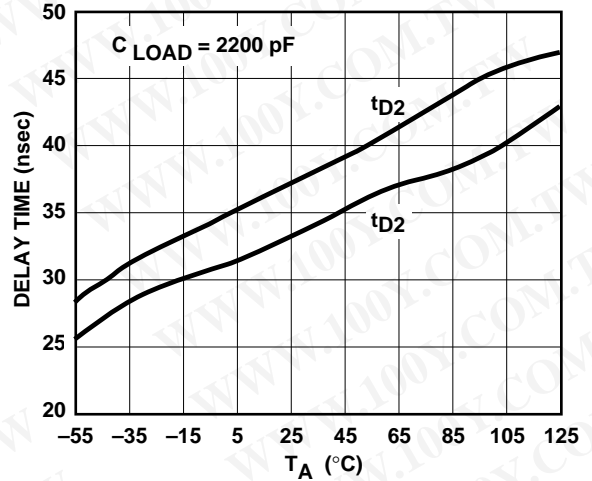
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TYPICAL CHARACTERISTICS (Cont.)

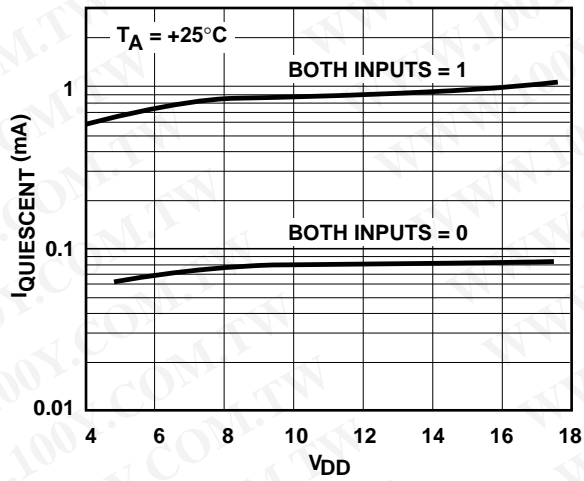
Propagation Delay Time vs. Supply Voltage



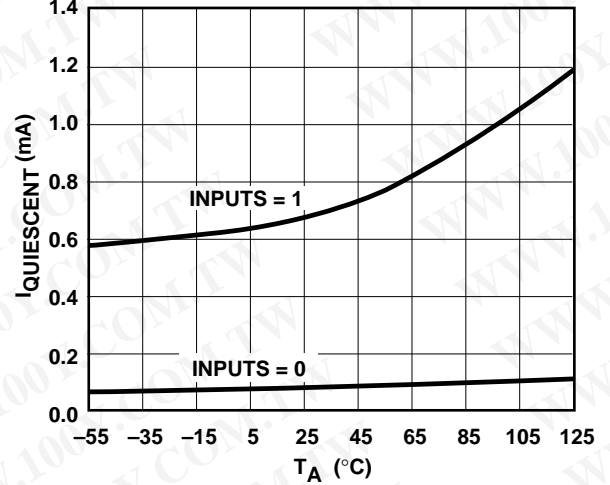
Delay Time vs. Temperature



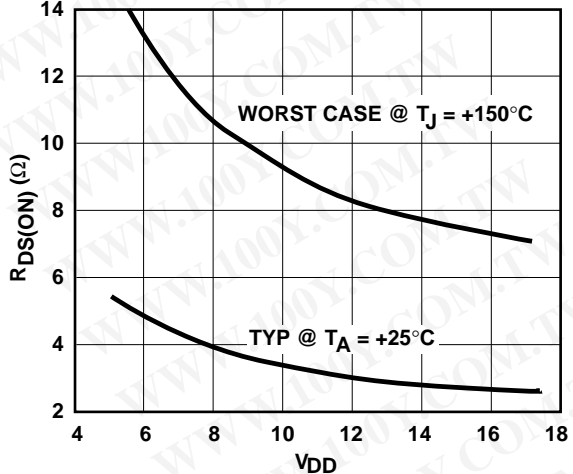
Quiescent Current vs. Supply Voltage



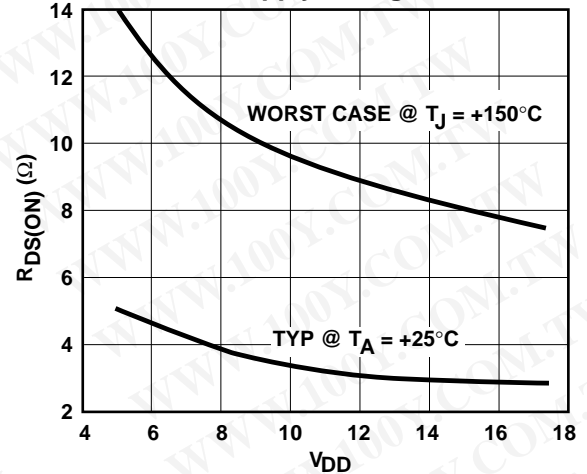
Quiescent Current vs. Temperature



Output Resistance (Output High) vs. Supply Voltage



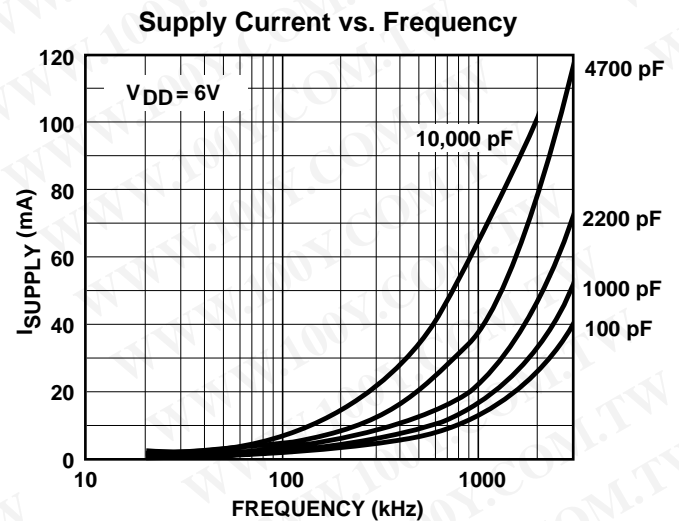
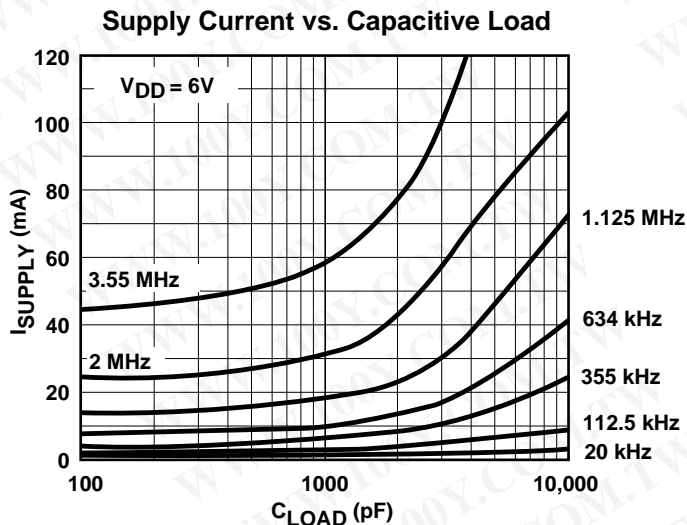
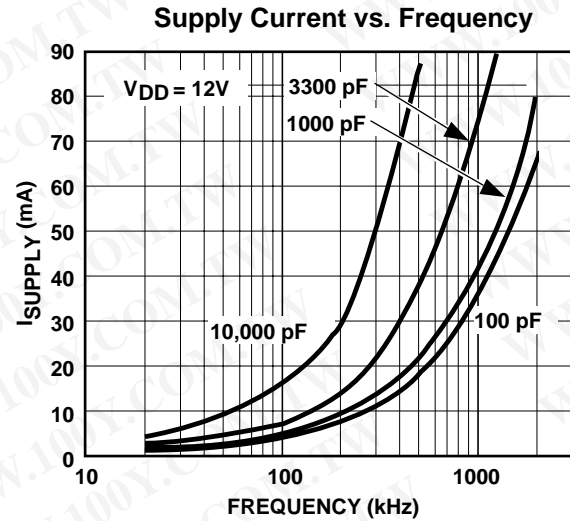
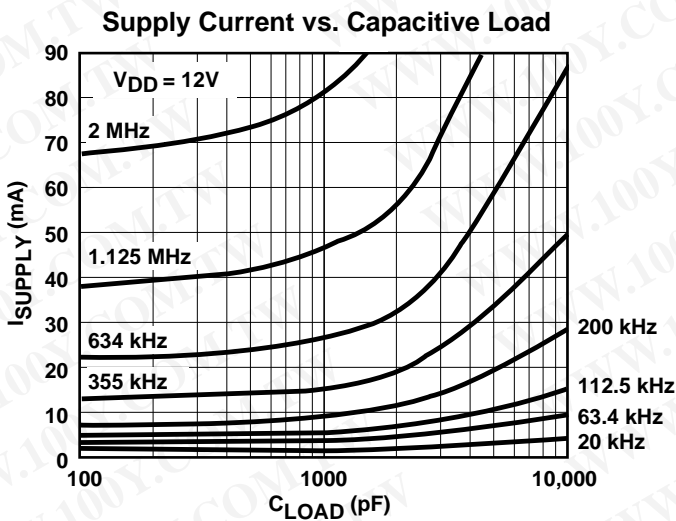
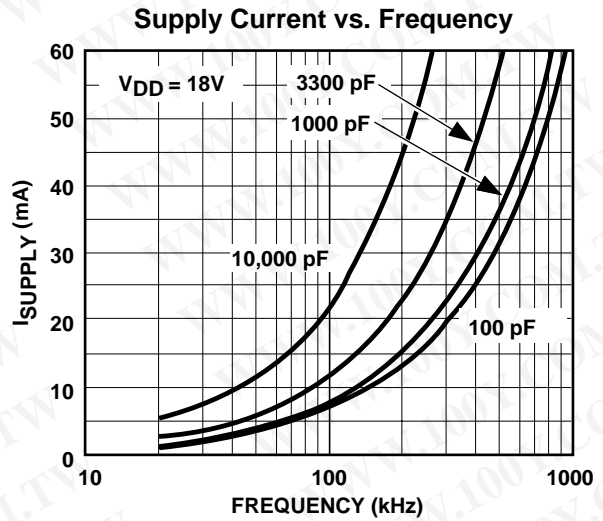
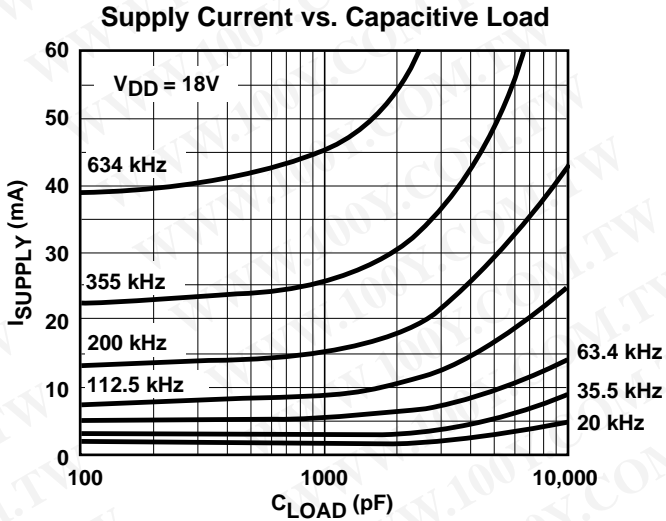
Output Resistance (Output Low) vs. Supply Voltage



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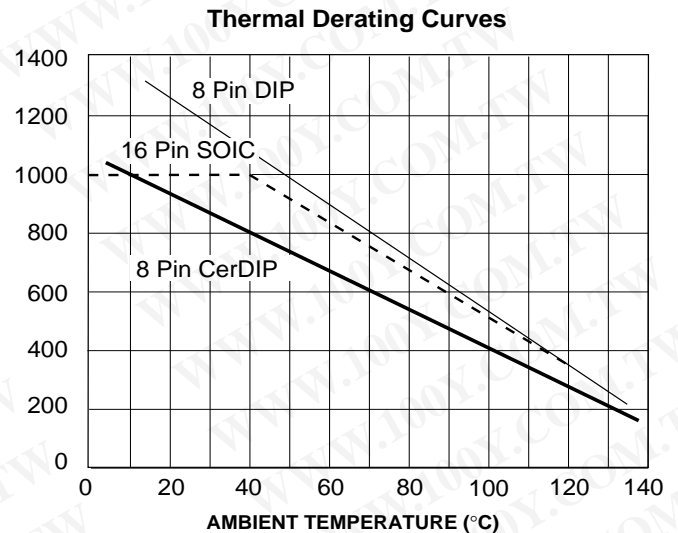
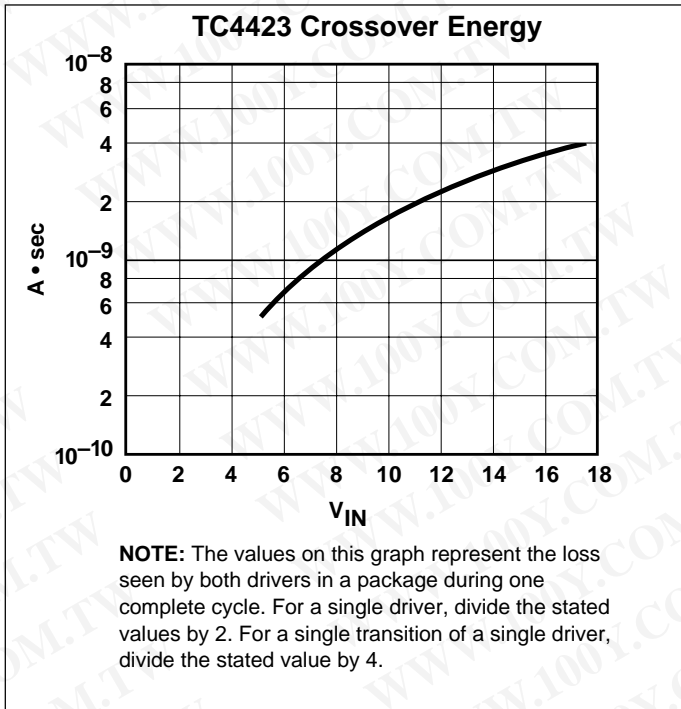
TC4423
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TC4425

SUPPLY CURRENT CHARACTERISTICS (Load on Single Output Only)



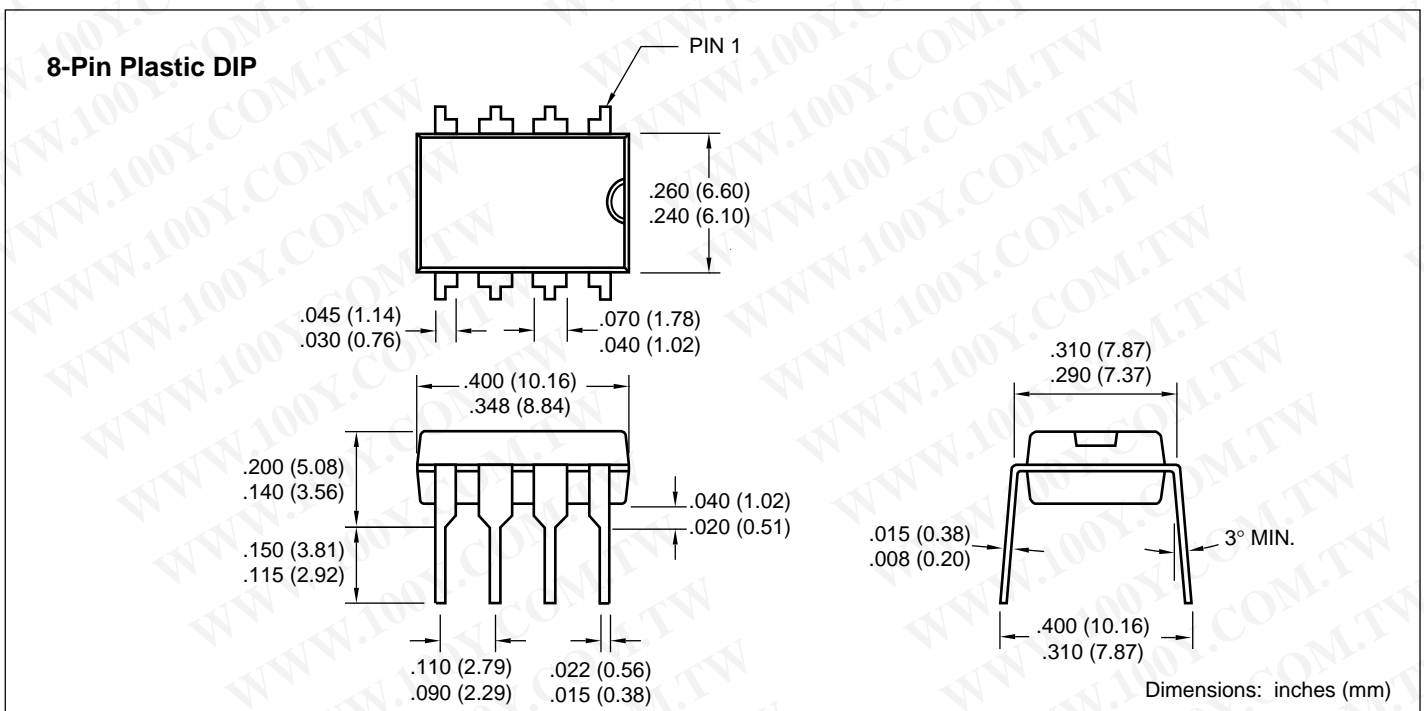
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TC4425



*Static-sensitive device. Unused devices must be stored in conductive material. Protect devices from static discharge and static fields. Stresses above those listed under Absolute Maximum Ratings (See page 2) may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to Absolute Maximum Rating Conditions for extended periods may affect device reliability.

PACKAGE DIMENSIONS

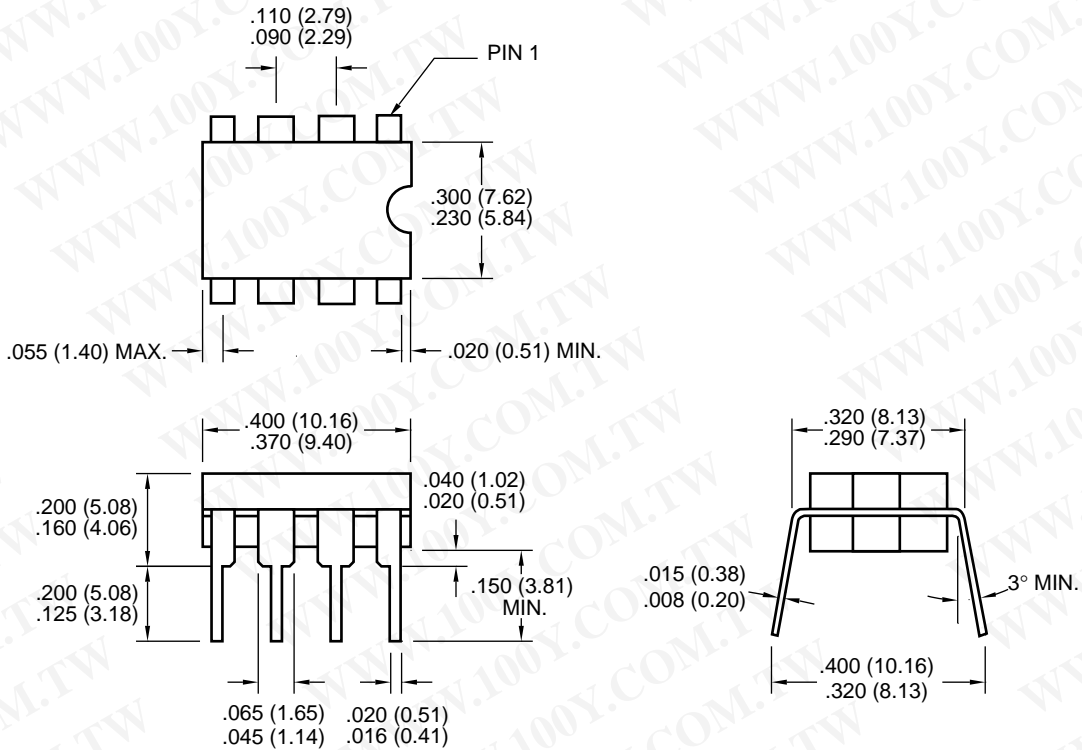


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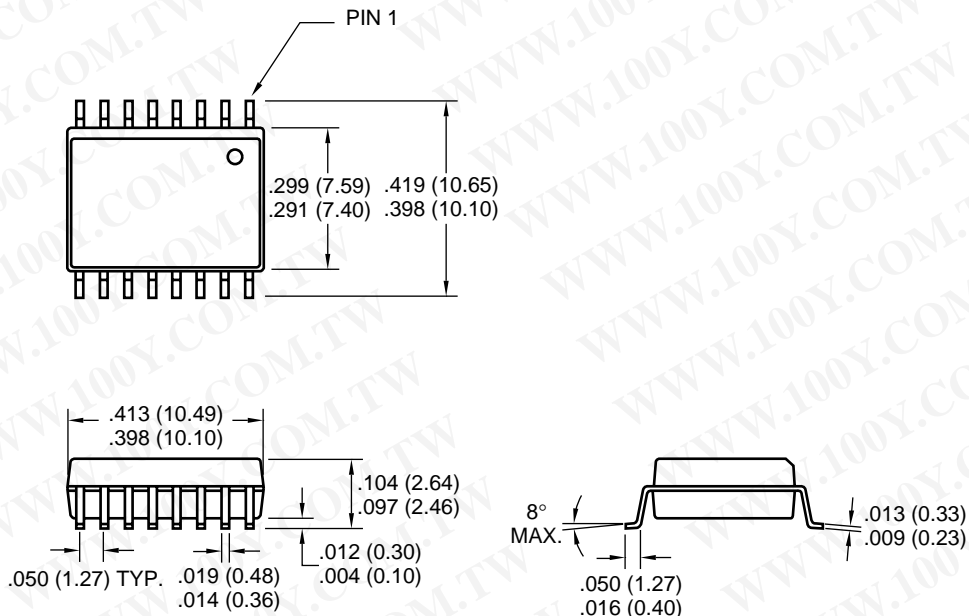
TC4423
TC4424
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PACKAGE DIMENSIONS (Cont.)

8-Pin CerDIP



16-Pin Plastic SOIC (Wide)



Dimensions: inches (mm)